Electronic Supplementary Material (ESI) for Journal of Materials Chemistry A.

High-performance capacitors based on the $NaNbO_3$ nanowires /poly(vinylidene fluoride) nanocomposites

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Supporting information 1

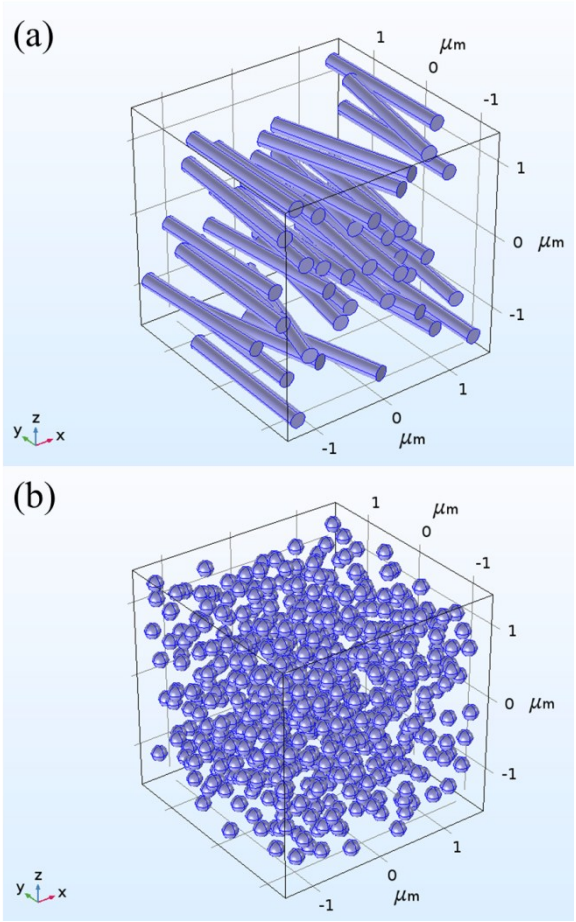

Figure S1 Three-dimensional models of the simulation system for (a) 9 vol% NN nanowires/PVDF and (b) 9 vol% NN nanoparticles/PVDF composite films.

Supporting information 2

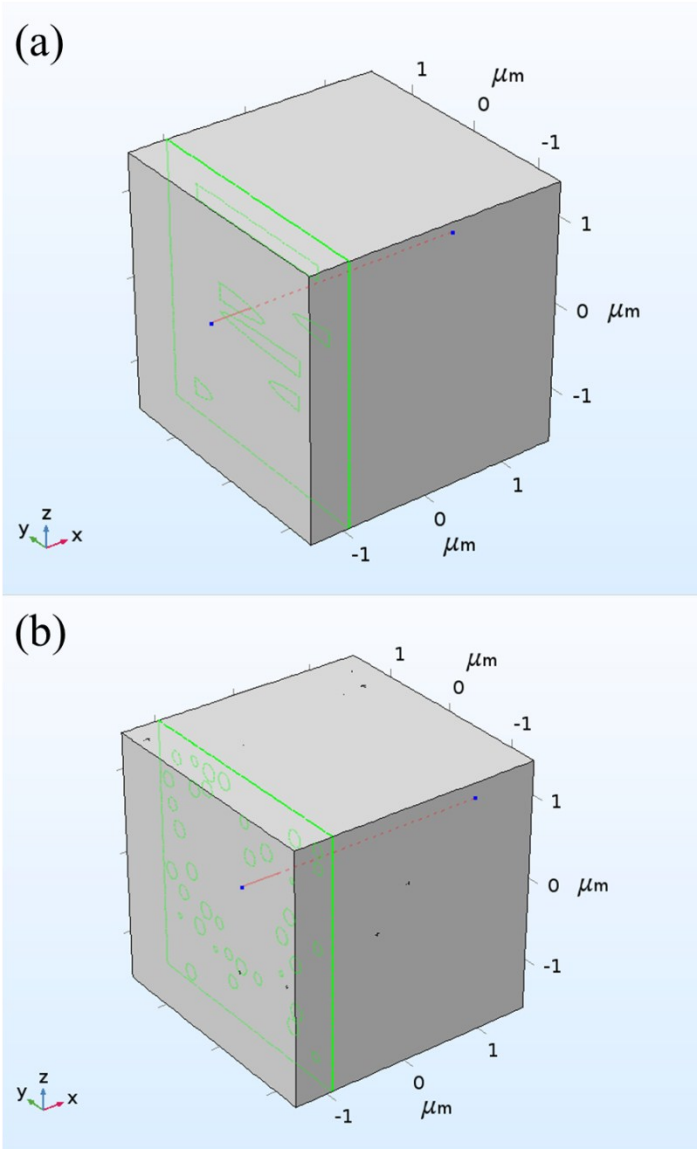

Figure S2 Cross-section images models of electric potential, local electric field, and leakage current density simulated for the (a) 9 vol% NN nanowires/PVDF nanocomposites and (b) 9 vol% NN nanoparticles/PVDF nanocomposites.

Supporting information 3

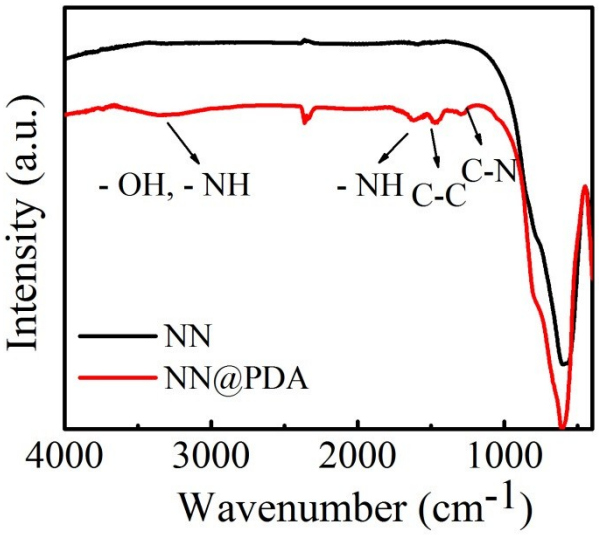

Figure S3 FT-IR spectrum of NN-PDA nanowires and NN nanowires.

Supporting information 4

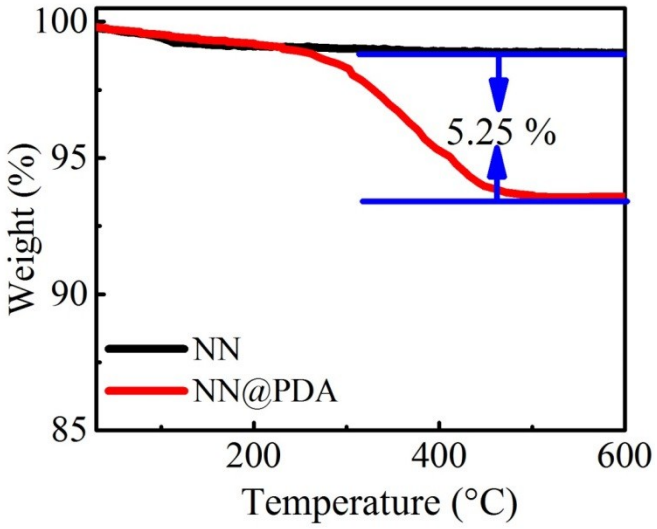

Figure S4 TGA curves of NN-PDA nanowires and NN nanowires.

Supporting information 5

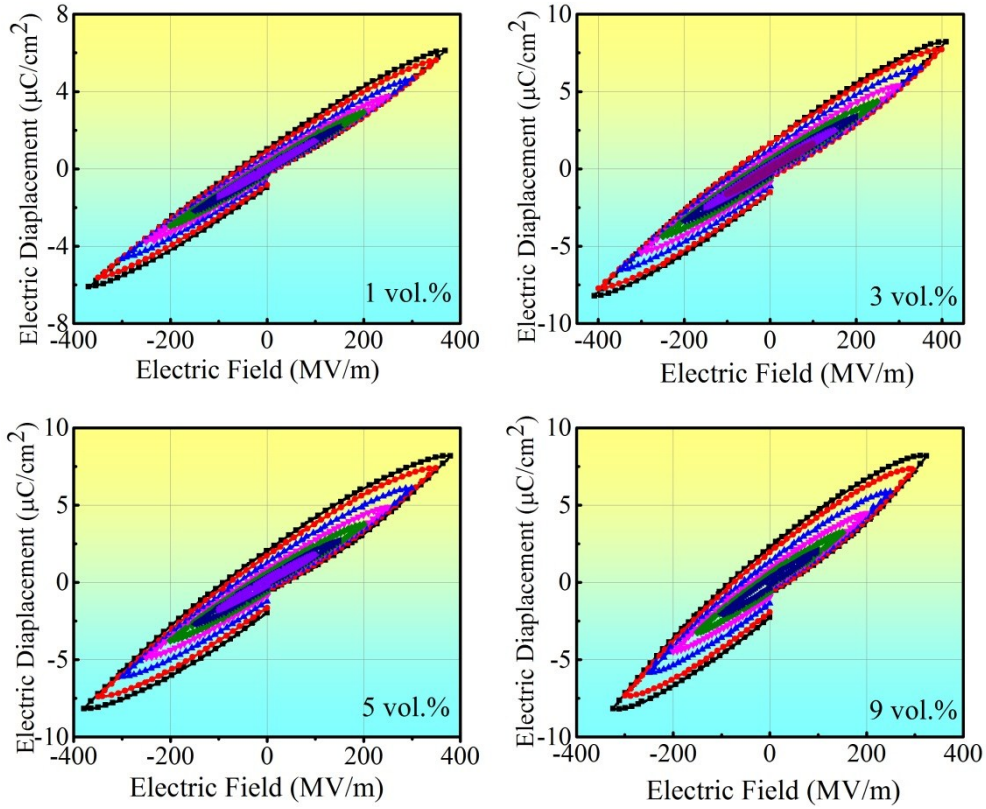

Figure S5 D-E curves of NN@PDA nanowires/PVDF nanocomposites with different filler concentrations.